

EE CIRCUIT EQUATIONS

Diode Signal

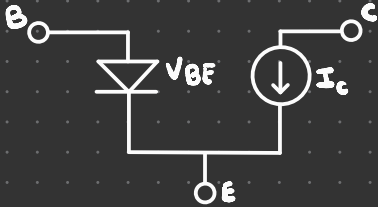


$$v(t) = V_0 + V_p \cos(\omega t)$$

$$i(t) = I_0 + \frac{I_0}{V_T} V_p \cos(\omega t)$$

$$I_0 = I_s e^{V_0/V_T}$$

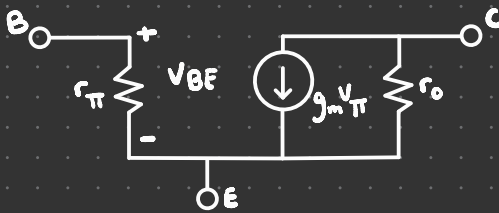
BJT Large Signal



$$V_{BE} = \frac{I_C}{\beta}$$

$$I_C = I_s e^{V_{BE}/V_T} \left(1 + \frac{V_{CE}}{V_A}\right)$$

BJT small signal

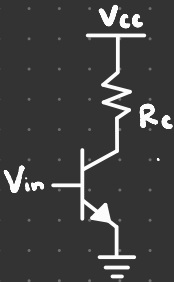


$$r_{\pi} = \beta / g_m$$

$$g_m = I_C / V_T$$

$$r_o = V_A / I_C$$

Common emitter



$$r_{in} = r_{\pi}$$

$$r_{out} = r_o \parallel R_C$$

$$A_v = -g_m (R_C \parallel r_o)$$

Intrinsic Gain



$$A_v = V_A / V_T$$

Intrinsic Gain is the maximum gain possible if $R_C \rightarrow \infty$
w/ Ideal current source

Common emitter w/ Degeneration



$$R_{in} = r_{\pi} + (\beta + 1)R_e$$

$$R_{out} = R_c \parallel r_o$$

$$A_v = \frac{-R_c \parallel r_o}{1/g_m + R_e}$$

Common Base



$$R_{in} = 1/g_m$$

$$R_{out} = R_c \parallel r_o$$

$$A_v = g_m (R_c \parallel r_o)$$

Common collector / Emitter Follower



$$R_{in} = r_{\pi} + (\beta + 1)R_e$$

$$R_{out} = R_e \parallel \left(\frac{R_s}{\beta + 1} + 1/g_m \right), R_s = \text{source impedance}$$

$$A_v = R_e / \left(\frac{1}{g_m} + R_e \right)$$

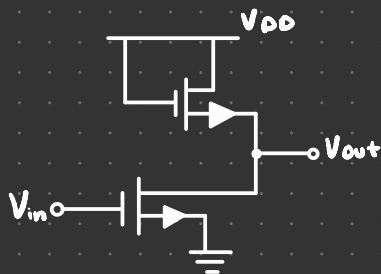
Common Source



$$R_{out} = R_D \parallel r_o$$

$$A_v = -g_m (R_D \parallel r_o)$$

common source w/ Diode Load



$$A_v = \sqrt{\frac{(W/L)_1}{(W/L)_2}}$$

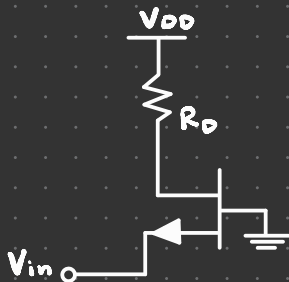
common source w/ Degeneration



$$R_{out} = r_o (g_m R_S + 1)$$

$$A_v = \frac{-R_D \parallel r_o}{(1/g_m + R_S)}$$

common gate

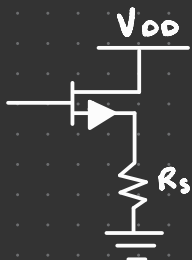


$$R_{in} = 1/g_m$$

$$R_{out} = R_D \parallel r_o$$

$$A_v = g_m (R_D \parallel r_o)$$

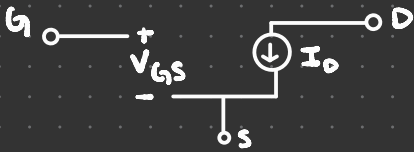
Common Drain (source Follower)



$$R_{out} = 1/g_m \parallel r_o \parallel R_S$$

$$A_v = \frac{R_S \parallel r_o}{1/g_m + R_S \parallel r_o}$$

Mosfet Large Signal



$$V_{DS} > V_{GS} - V_{TH} \rightarrow I_D = ?$$

$$V_{DS} < V_{GS} - V_{TH} \rightarrow I_D = ?$$



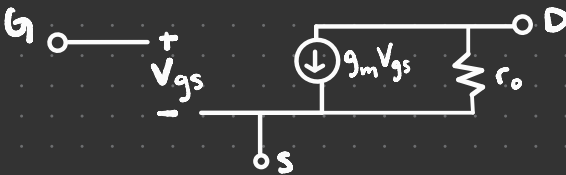
$$V_{DS} \ll V_{GS} - V_{TH} \rightarrow I_D = ?$$

$$\text{Saturation } I_D = \frac{1}{2} \mu_n C_{ox} \frac{W}{L} (V_{GS} - V_{TH}) (1 + \lambda V_{DS})$$

$$\text{Triode } I_D = \frac{1}{2} \mu_n C_{ox} \frac{W}{L} [2(V_{GS} - V_{TH})V_{DS} + V_{DS}^2]$$

$$\text{Deep Triode } R_{on} = [\mu_n C_{ox} \frac{W}{L} (V_{GS} - V_{TH})]^{-1}$$

MOSFET small signal

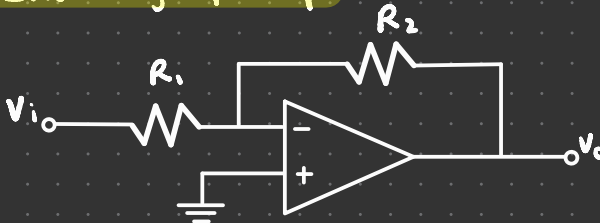


$$g_m = \mu_n C_{ox} \frac{W}{L} (V_{GS} - V_{TH})$$

$$r_o = \frac{1}{\lambda I_D}$$

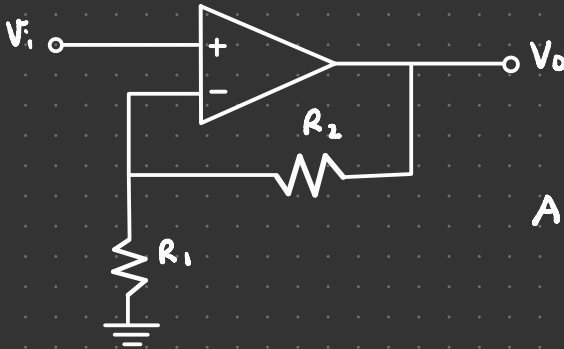
$$= \frac{\sqrt{2 \mu_n C_{ox} \frac{W}{L} I_D}}{I_D} = \frac{2 I_D}{V_{GS} - V_{TH}}$$

Inverting Op-Amp



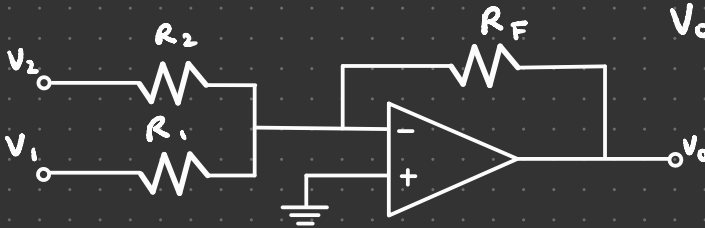
$$A_v = \frac{-R_2}{R_1}$$

Non-inverting Op-Amp



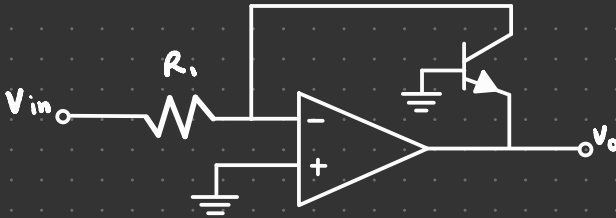
$$A_v = 1 + \frac{R_2}{R_1}$$

Summing Op-Amp



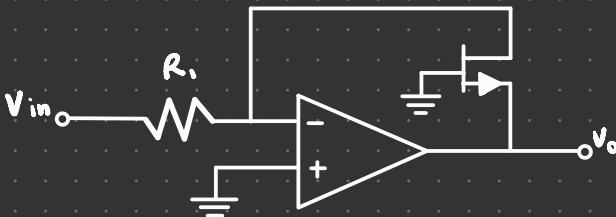
$$V_o = -R_F \left(\frac{V_1}{R_1} + \frac{V_2}{R_2} + \dots \right)$$

Logarithmic Op-Amp



$$V_o = V_T \ln \left(\frac{V_{in}}{R_1 I_s} \right)$$

Square Root Op-Amp



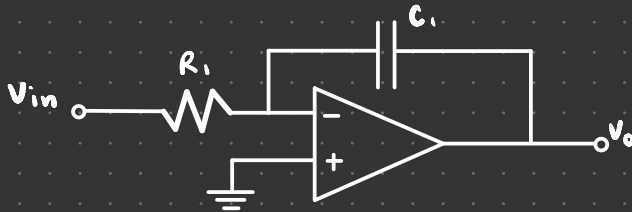
$$V_o = \sqrt{\frac{2 V_{in}}{\mu_n c_{ox} \frac{W}{L} R_1}} - V_{TH}$$

Differentiator Op-Amp



$$V_o = -C_1 R_1 \frac{dV_{in}}{dt}$$

Integrator Op-Amp



$$V_o = -\frac{1}{C_1} \int_0^T \frac{V_{in}}{R_1} dt$$

Bode's Rules

QUESTIONS

- * what happens to $|H(j\omega)|$ at poles and zeroes
- * what happens to angle $H(j\omega)$ at poles and zeroes
- * what happens at nodes with an impedance R_j and C_j to ground

ANSWERS

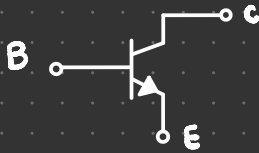
- * poles at $\omega = \omega_{pn}$ lower the slope of $|H(j\omega)|$ by 20dB/decade
- * zeroes at $\omega = \omega_{zn}$ increase the slope of $|H(j\omega)|$ by 20dB/decade
- * poles create -45 degree shift at $\omega = \omega_p$, and approach -90 degree shift at $\omega = 10 \cdot \omega_p$
- * zeroes create a +45 degree shift at $\omega = \omega_z$, and approach +90 degree shift at $\omega = 10 \cdot \omega_z$

Miller Theorem



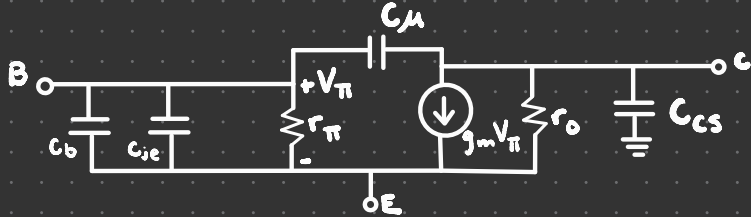
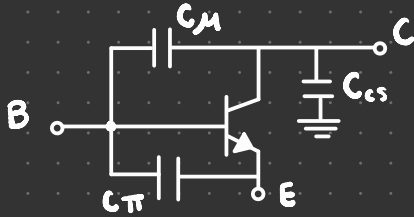
$$I_f A_v = \frac{V_2}{V_1}, \quad Z_1 = \frac{Z_F}{1 - A_v}, \quad Z_2 = \frac{Z_F}{1 - 1/A_v}$$

BJT High Frequency



Question: Draw the high frequency small signal model & device parasitics

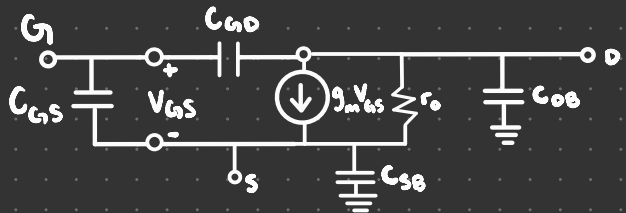
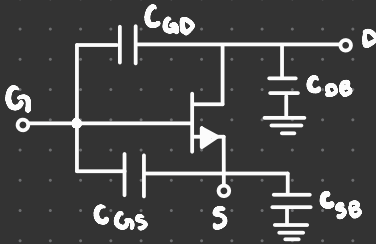
Answer:



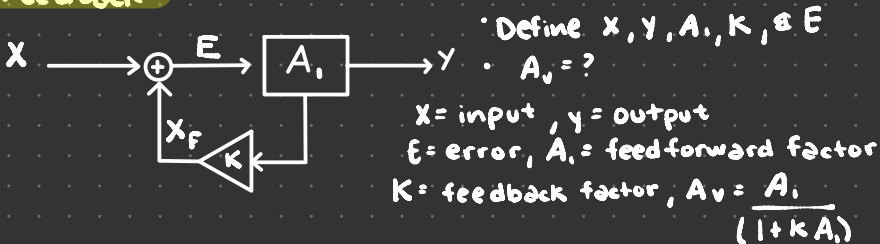
MOSFET High Frequency



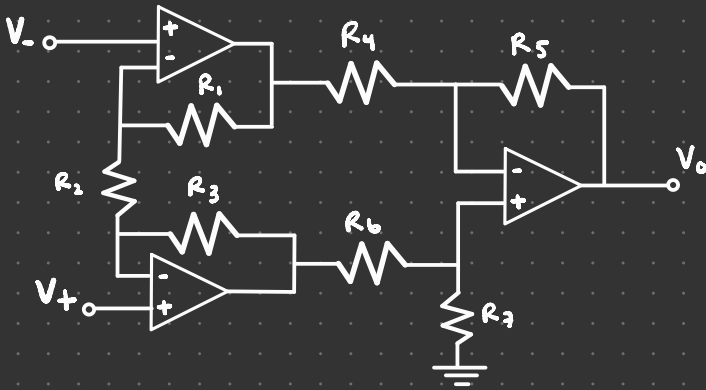
Question: Draw the high frequency small signal model & device parasitics



Feedback



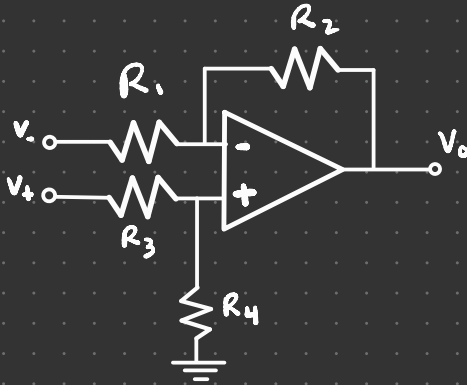
Instrumentation Op-Amp



$$\text{If } R_1 = R_3 \\ \& \frac{R_5}{R_4} = \frac{R_2}{R_6}$$

$$V_o = (V_o - V_+) \left(1 + 2 \frac{R_1}{R_2} \right) \frac{R_5}{R_4}$$

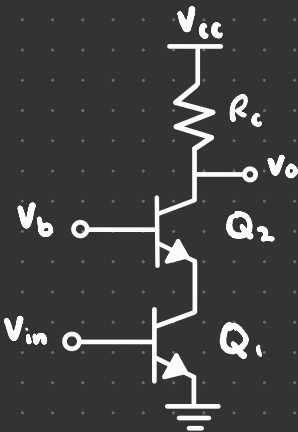
Difference Op-Amp



$$V_o = V_+ \left(\frac{R_4}{R_3 + R_4} \right) \left(\frac{R_2 + R_1}{R_1} \right) - (V_-) \frac{R_2}{R_1}$$

$$\text{If } \frac{R_2}{R_1} = \frac{R_4}{R_3} = V_o = (V_+ - V_-) \frac{R_2}{R_1}$$

BJT Cascode

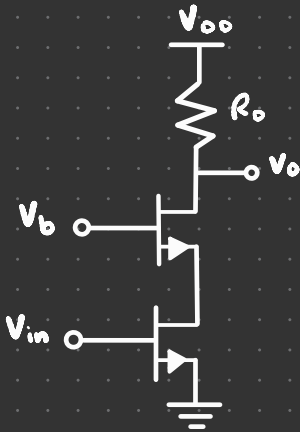


$$R_{in} = r_{\pi 1}$$

$$R_{out} = R_c \parallel [g_{m2} r_{o2} (r_{o1} \parallel r_{\pi 2}) + (r_{o1} \parallel r_{\pi 2})]$$

$$A_v = -g_{m1} R_{out}$$

MOSFET Cascode

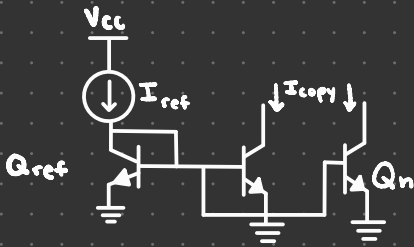


$$R_{in} = \infty$$

$$R_{out} = R_o \parallel [(1 + g_{m1} r_{o1}) r_{o2} + r_{o1}]$$

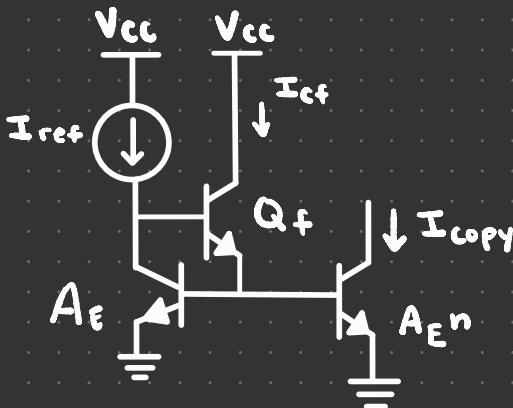
$$A_v = -g_{m1} R_{out}$$

BJT current mirror



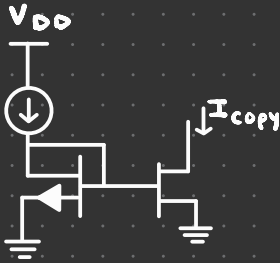
$$I_{copy} = \frac{n I_{ref}}{1 + \frac{1}{\beta}(n+1)}$$

BJT current mirror w/ feedback



$$I_{copy} = \frac{n I_{ref}}{1 + \frac{1}{\beta^2}(n+1)}$$

MOSFET current mirror



$$I_{copy} = I_{ref} \frac{(W/L)_{copy}}{(W/L)_{ref}}$$

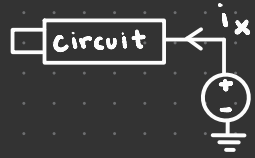
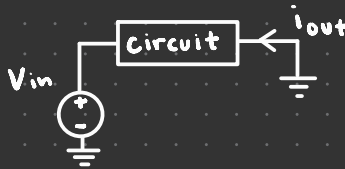
General Amplifier

For a general two part circuit, what is A_v ?

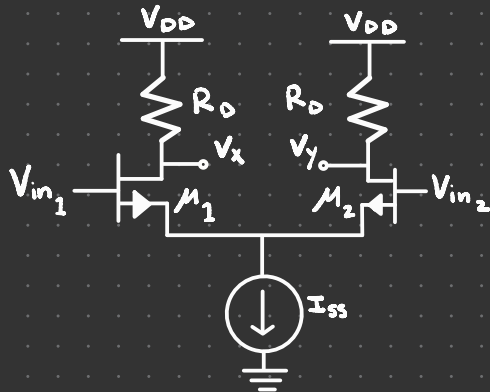
$$A_v = -G_m R_{out}$$

$$G_m = \left. \frac{i_{out}}{V_{in}} \right|_{V_{out}=0}$$

$$R_{out} = \left. \frac{V_x}{i_x} \right|_{V_{in}=0}$$



MOSFET Differential Pair Large Symbol



$$V_x - V_y = -\frac{1}{2} R_o \mu_n C_{ox} \frac{W}{L} (V_{in1} - V_{in2}) \sqrt{\frac{4I_{ss}}{\mu_n C_{ox} \frac{W}{L}} - (V_{in1} - V_{in2})^2}$$

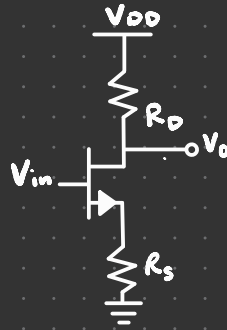
V_x & V_y hit the rails when

$$|V_{in1} - V_{in2}| = \sqrt{\frac{2I_{ss}}{\mu_n C_{ox} \frac{W}{L}}}$$

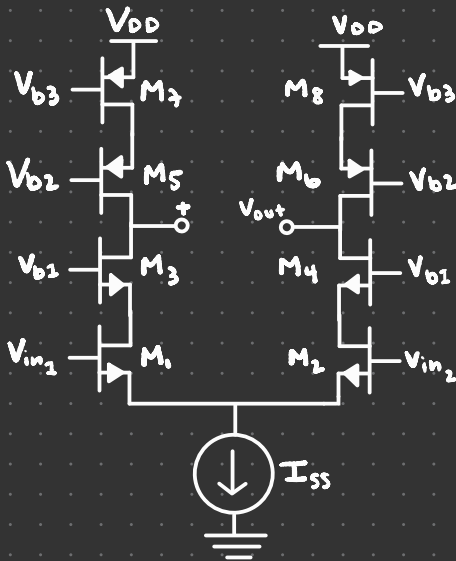
where $I_{D1} = I_{ss}$

and $I_{D2} = 0$

MOSFET Differential Pair Small signal



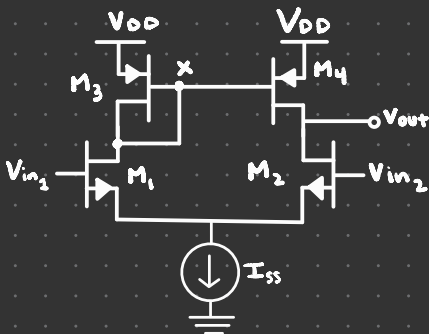
MOSFET Telescopic Differential Pair



$$A_v = -g_{m1} [(g_{m3} r_{o3} + 1) r_{o1} + r_{o3}] // \dots$$

$$\dots [(g_{m4} r_{o4} + 1) r_{o5} + r_{o4}]$$

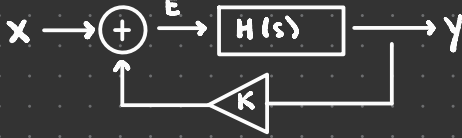
MOSFET Differential w/ Active Load



$$A_v = \frac{V_{out}}{V_{in1} - V_{in2}} = g_{m_n} (r_{on} // r_{op})$$

Barkhausen's Criteria

Consider System:



System $H(j\omega) = H(s)$ oscillates

$$\text{at } \omega_1 \text{ where } |KH(j\omega_1)| = 1 \text{ \underline{\underline{and}}} \\ \angle KH(j\omega_1) = -180^\circ$$

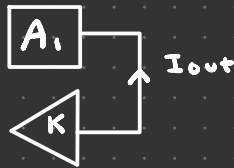
Phase Margin

- Gain crossover ω_{gx} when $|KH(j\omega)| = 1$
- Phase crossover ω_{px} when $\angle KH(j\omega) = -180^\circ$
- Phase margin is how far away ω_{gx} is from ω_{px} , i.e. $\angle H(j\omega_{gx}) + 180^\circ$

Feedback sense-current

How is current output sensed? How is the output impedance affected?
Draw current sense diagram

CURRENT IS SENSED IN SERIES

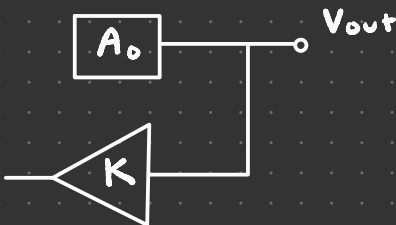


$$Z_r = R_{out} (1 + KA_1)$$

Feedback sense-voltage

How is voltage output sensed? How is the output impedance affected? Draw voltage sense diagram

VOLTAGE IS SENSED IN PARALLEL (SHUNT)

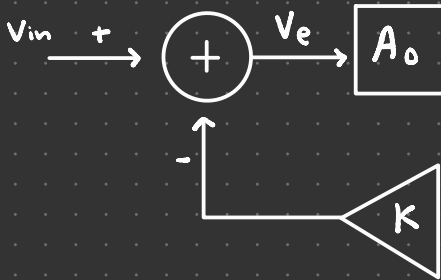


$$Z_r = \frac{R_{out}}{1 + KA_0}$$

Feedback return - voltage

- How is voltage feedback returned?
- How is the input impedance affected?
- Draw voltage return diagram

VOLTAGE IS RETURNED IN SERIES

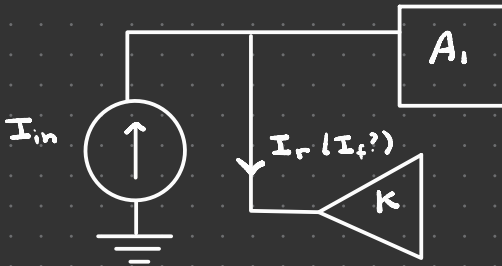


$$Z_i = R_{in} (1 + K A_0)$$

Feedback return - current

- How is current feedback returned?
- How is the input impedance affected?
- Draw current return diagram

CURRENT IS RETURNED IN PARALLEL (SHUNT)



$$Z_i = \frac{R_{in}}{H K A_1}$$

Topics to know

$$y(1 + A_1 K) = A_1 x \rightarrow \frac{y}{x} = \frac{A_1}{1 + A_1 K}, \quad y + A_1 K y = A_1 x, \quad y = A_1 E, \quad E = x - x_F$$

- Summing
- Logarithmic
- Square root
- Differential
- Instrumentation
- Differentiator
- Integrator

$$x_F = K y, \quad y = A_1 (x - K y)$$

- High Freq. Parasitics
- Miller effect
- cascodes
- current mirrors
- Diff pair

- Feedback topologies
- General def. for C_{in} & R_{out}
- Bode's rules
- Transit frequency
- Barkhausen
- Stability